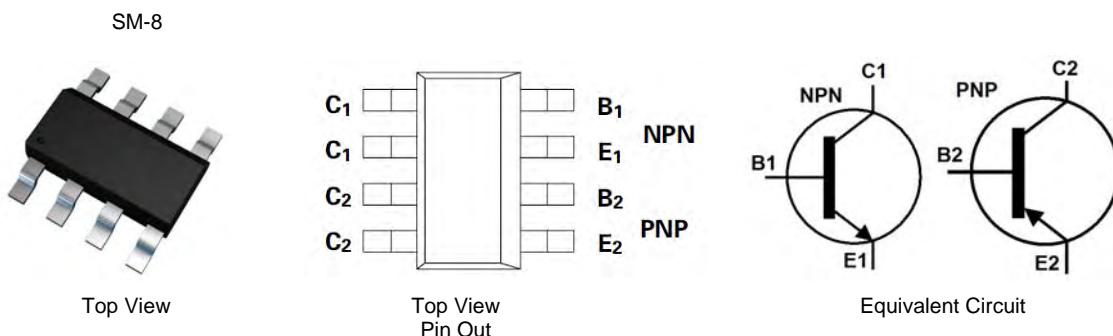


COMPLEMENTARY MEDIUM POWER HIGH GAIN TRANSISTOR IN SM-8 PACKAGE
Features

- NPN Transistor
 - $BV_{CEO} > 45$
 - $V_{CE(sat)} < 100mV @ I_C = 100mA$
 - Continuous Current $I_C = 2A$
- PNP Transistor
 - $BV_{CEO} > -40V$
 - $V_{CE(sat)} < 250mV @ I_C = -500mA$
 - Continuous Current $I_C = -2A$
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

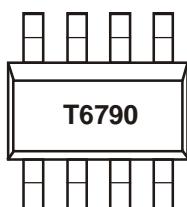
- Case: SM-8 (8 LEAD SOT223)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (E3)
- Weight: 0.117 grams (approximate)


Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZDT6790TA	T6790	7	12	1,000
ZDT6790TC	T6790	13	12	4,000

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <http://www.diodes.com>

Marking Information


T6790 = Product Type Marking Code

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

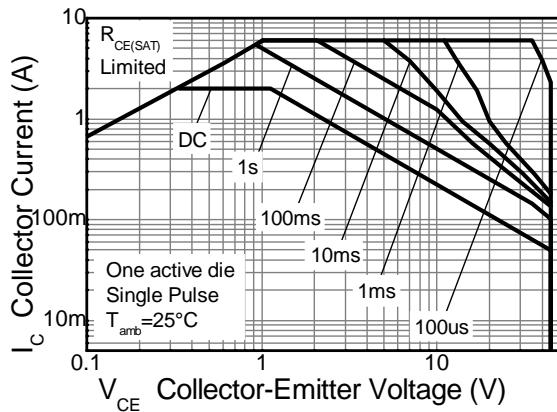
Characteristic	Symbol	NPN	PNP	Unit
Collector-Base Voltage	V_{CBO}	45	-50	V
Collector-Emitter Voltage	V_{CEO}	45	-40	V
Emitter-Base Voltage	V_{EBO}	6	-6	V
Continuous Collector Current	I_C	2	-2	A
Peak Pulse Current (Note 5)	I_{CM}	6	-6	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

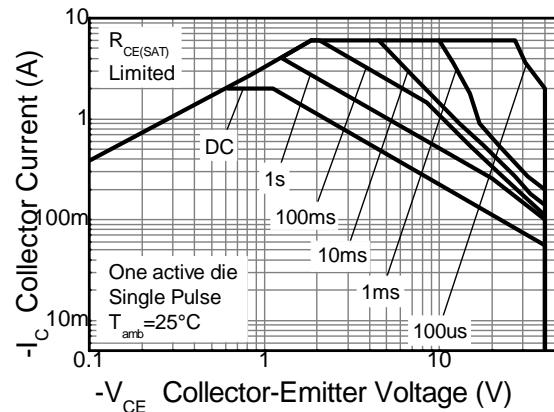
Characteristic	Symbol	Value	Unit
Collector Power Dissipation (Note 5)	P_D	2.25	W
(Note 6)		2.75	
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	55.60	°C/W
(Note 6)		45.50	
Thermal Resistance, Junction to Leads (Note 7)	$R_{\theta JL}$	30.68	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes:
5. For the device with any single die active, mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions .
6. For the device with both die active, mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).

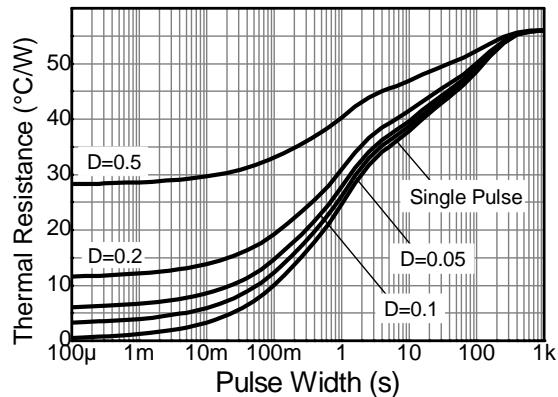
Thermal Characteristics



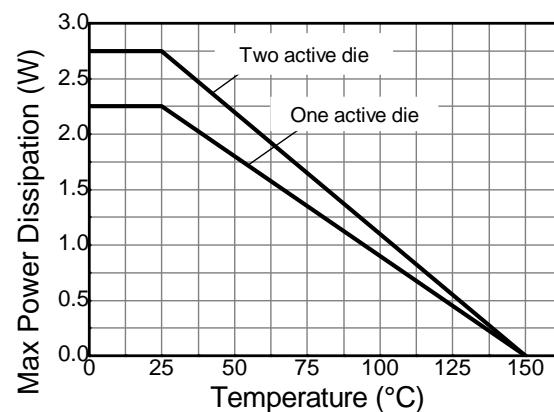
NPN Safe Operating Area



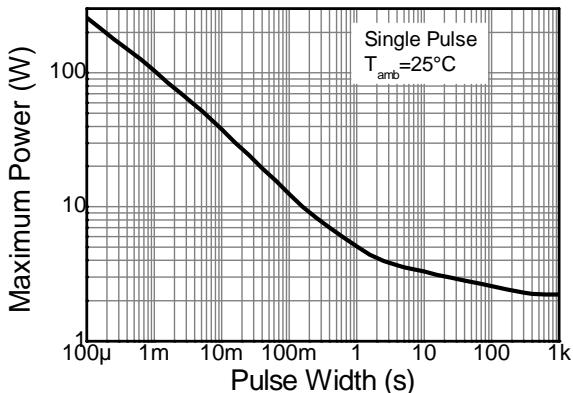
PNP Safe Operating Area



Transient Thermal Impedance



Derating Curve



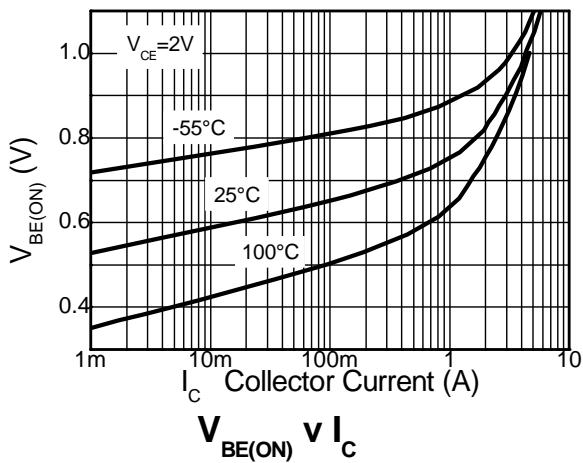
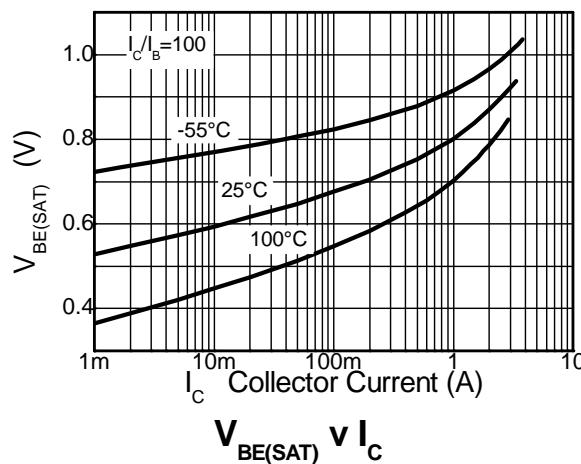
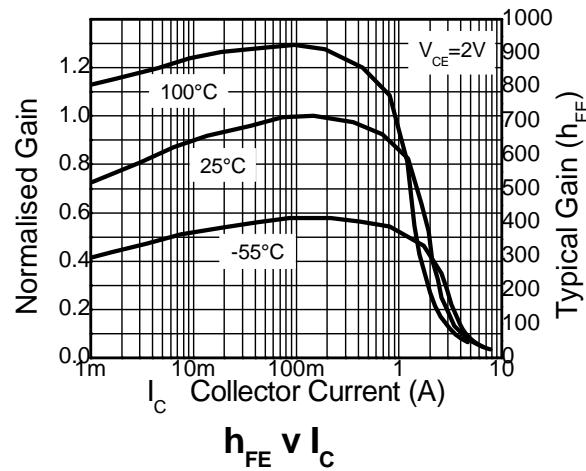
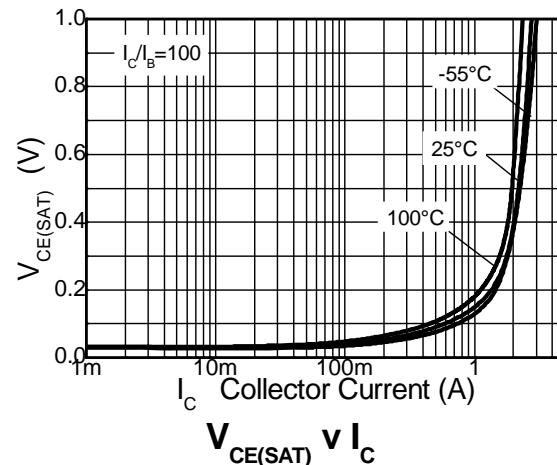
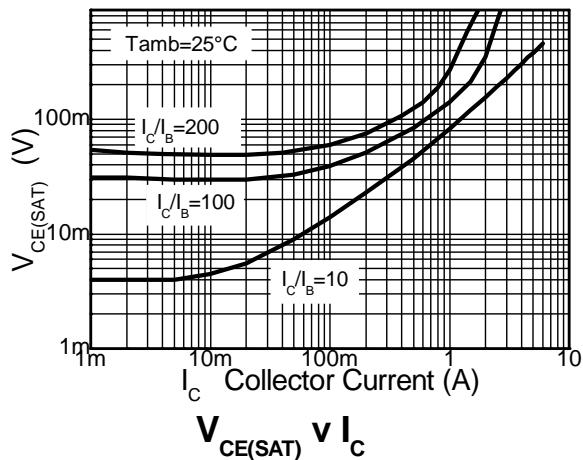
Pulse Power Dissipation

NPN - Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	45	—	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 8)	BV_{CEO}	45	—	—	V	$I_C = 10\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	6	—	—	V	$I_E = 100\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	100	nA	$V_{\text{CB}} = 35\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	100	nA	$V_{\text{EB}} = 5\text{V}$
DC Current Transfer Static Ratio (Note 8)	h_{FE}	500 400 150	— — —	— — —	—	$I_C = 100\text{mA}, V_{\text{CE}} = 2\text{V}$ $I_C = 1\text{A}, V_{\text{CE}} = 2\text{V}$ $I_C = 2\text{A}, V_{\text{CE}} = 2\text{V}$
Collector-Emitter Saturation Voltage (Note 8)	$V_{\text{CE}(\text{sat})}$	— —	— —	100 500	mV	$I_C = 100\text{mA}, I_B = 0.5\text{mA}$ $I_C = 1\text{A}, I_B = 5\text{mA}$
Base-Emitter Saturation Voltage (Note 8)	$V_{\text{BE}(\text{sat})}$	—	—	900	mV	$I_C = 1\text{A}, I_B = 10\text{mA}$
Base-Emitter Turn-on Voltage (Note 8)	$V_{\text{BE}(\text{on})}$	—	—	900	mV	$I_C = 1\text{A}, V_{\text{CE}} = 2\text{V}$
Transistor Frequency (Note 8)	f_T	150	—	—	MHz	$I_C = 50\text{mA}, V_{\text{CE}} = 5\text{V}, f = 50\text{MHz}$
Input Capacitance	C_{ib0}	—	200	—	pF	$V_{\text{EB}} = 0.5\text{V}, f = 1\text{MHz}$
Output Capacitance	C_{ob0}	—	16	—	pF	$V_{\text{CB}} = 10\text{V}, f = 1\text{MHz}$
Switching Time	t_{on} t_{off}	—	33 1300	—	ns ns	$V_{\text{CC}} = 10\text{V}, I_C = 500\text{mA}, I_{B1} = 50\text{mA}, I_{B2} = 50\text{mA}$

Note: 8. Measured under pulsed conditions. Pulse width = 300 μs . Duty cycle $\leq 2\%$.

NPN – Typical Electrical Characteristics

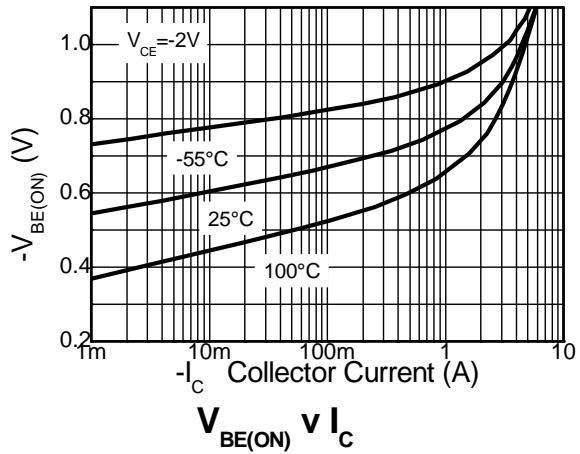
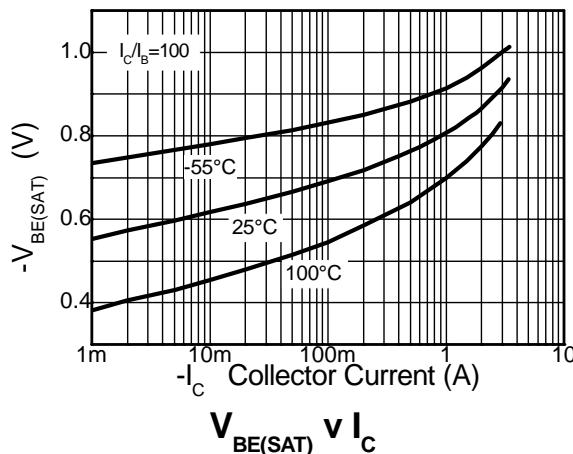
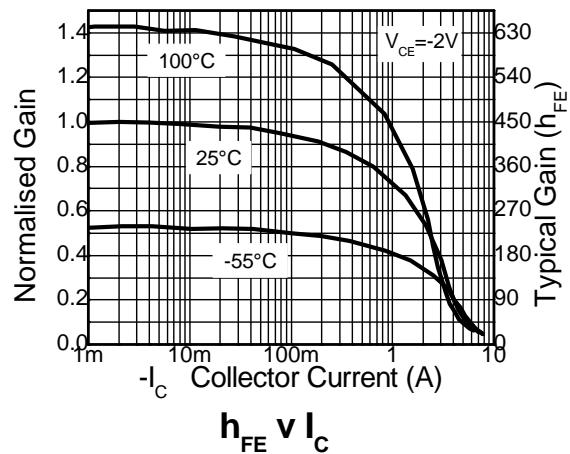
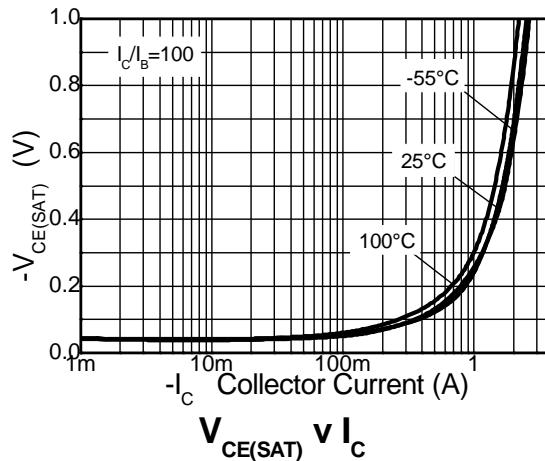
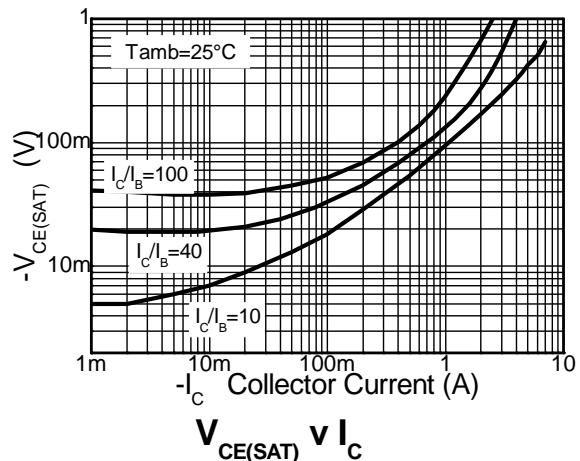


PNP - Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

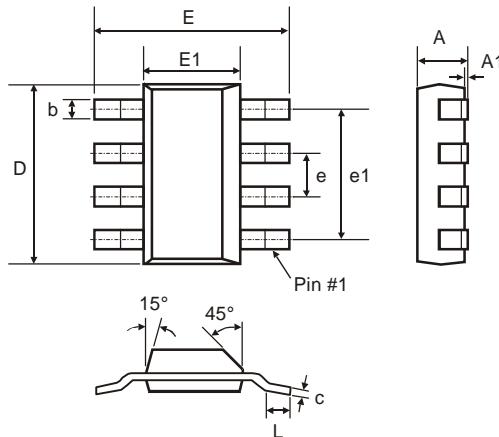
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-50	—	—	V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Notes 8)	BV_{CEO}	-40	—	—	V	$I_C = -10\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-6	—	—	V	$I_E = -100\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	-100	nA	$V_{\text{CB}} = -30\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	-100	nA	$V_{\text{EB}} = -5\text{V}$
DC Current Transfer Static Ratio (Notes 8)	h_{FE}	300 250 200 150	— — — —	800 — — —	—	$I_C = -10\text{mA}, V_{\text{CE}} = -2\text{V}$ $I_C = -500\text{mA}, V_{\text{CE}} = -2\text{V}$ $I_C = -1\text{A}, V_{\text{CE}} = -2\text{V}$ $I_C = -2\text{A}, V_{\text{CE}} = -2\text{V}$
Collector-Emitter Saturation Voltage (Notes 8)	$V_{\text{CE}(\text{sat})}$	—	— — —	-250 -450 -750	mV	$I_C = -500\text{mA}, I_B = -5\text{mA}$ $I_C = -1\text{A}, I_B = -10\text{mA}$ $I_C = -2\text{A}, I_B = -50\text{mA}$
Base-Emitter Saturation Voltage (Notes 8)	$V_{\text{BE}(\text{sat})}$	—	—	-1000	mV	$I_C = -1\text{A}, I_B = -10\text{mA}$
Base-Emitter Turn-on Voltage (Notes 8)	$V_{\text{BE}(\text{on})}$	—	-750	—	mV	$I_C = -1\text{A}, V_{\text{CE}} = -2\text{V}$
Transitional Frequency (Notes 8)	f_T	100	—	—	MHz	$I_C = -50\text{mA}, V_{\text{CE}} = -5\text{V}, f = 50\text{MHz}$
Input Capacitance	C_{ibo}	—	225	—	pF	$V_{\text{EB}} = -0.5\text{V}, f = 1\text{MHz}$
Output Capacitance	C_{obo}	—	24	—	pF	$V_{\text{CB}} = -10\text{V}, f = 1\text{MHz}$
Switching Time	t_{on} t_{off}	—	35 600	—	ns	$V_{\text{CC}} = -10\text{V}, I_C = -500\text{mA}, I_{\text{B1}} = -50\text{mA}, I_{\text{B2}} = -50\text{mA}$

Notes: 8. Measured under pulsed conditions. Pulse width = 300 μs . Duty cycle $\leq 2\%$.

PNP – Typical Electrical Characteristics



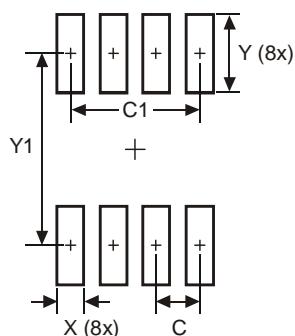
Package Outline Dimensions



SM-8			
Dim	Min	Max	Typ
A	—	1.7	—
A1	0.02	0.1	—
b	—	0.7	—
c	0.24	0.32	—
D	6.3	6.7	—
e	—	—	1.53
e1	—	—	4.59
E	6.7	7.3	—
E1	3.3	3.7	—
L	0.9	—	—

All Dimensions in mm

Suggested Pad Layout



Dimensions	Value (in mm)
C	1.52
C1	4.6
X	0.95
Y	2.80
Y1	6.80

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2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

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